Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
Between 1.000 inches and 1.065 inches	
Overall Diameter:	
Between 2.246 inches and 2.250 inches	
Mounting Method:	
Compression	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristi	<b>c</b> :
1100.0 nonrepetitive peak reverse voltage,	peak total value and 1000.0 repetitive peak reverse voltage
Current Rating Per Characteristic:	
30.00 milliamperes forward current, average	e major and 30.00 milliamperes forward current, average any acceptable
Maximum Operating Tempurature Per Me	easurement Point:
125.0 degrees celsius junction	
Terminal Type And Quantity:	
2 insulated wire lead w/terminal lug and 1 c	ase
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	